

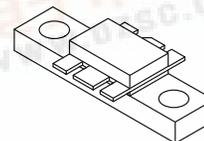
## The RF Line NPN Silicon RF Power Transistor

... designed for 12.5 volt UHF large-signal, **common-base** amplifier applications in industrial and commercial FM equipment operating in the range of 806–960 MHz.

- Specified 12.5 Volt, 870 MHz Characteristics
  - Output Power = 45 Watts
  - Power Gain = 4.5 dB Min
  - Efficiency = 60% Min
- Series Equivalent Large-Signal Characterization
- Internally Matched Input for Broadband Operation
- Tested for Load Mismatch Stress at All Phase Angles with 10:1 VSWR @ High Line and Rated Drive
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Silicon Nitride Passivated

**MRF847**

**45 W, 870 MHz  
RF POWER  
TRANSISTOR  
NPN SILICON**



CASE 319-07, STYLE 1

### MAXIMUM RATINGS

| Rating   | Symbol    | Value       | Unit                        |
|--|-----------|-------------|-----------------------------|
| Collector–Emitter Voltage  | $V_{CEO}$ | 16.5        | Vdc                         |
| Collector–Base Voltage   | $V_{CBO}$ | 38          | Vdc                         |
| Emitter–Base Voltage   | $V_{EBO}$ | 4.0         | Vdc                         |
| Collector Current — Continuous   | $I_C$     | 12          | Adc                         |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$     | 150<br>0.85 | Watts<br>$W/^\circ\text{C}$ |
| Storage Temperature Range  | $T_{stg}$ | –65 to +150 | $^\circ\text{C}$            |
| Junction Temperature   | $T_J$     | 200         | $^\circ\text{C}$            |

### THERMAL CHARACTERISTICS

| Characteristic                       | Symbol          | Max  | Unit                      |
|--------------------------------------|-----------------|------|---------------------------|
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 1.17 | $^\circ\text{C}/\text{W}$ |

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted.)

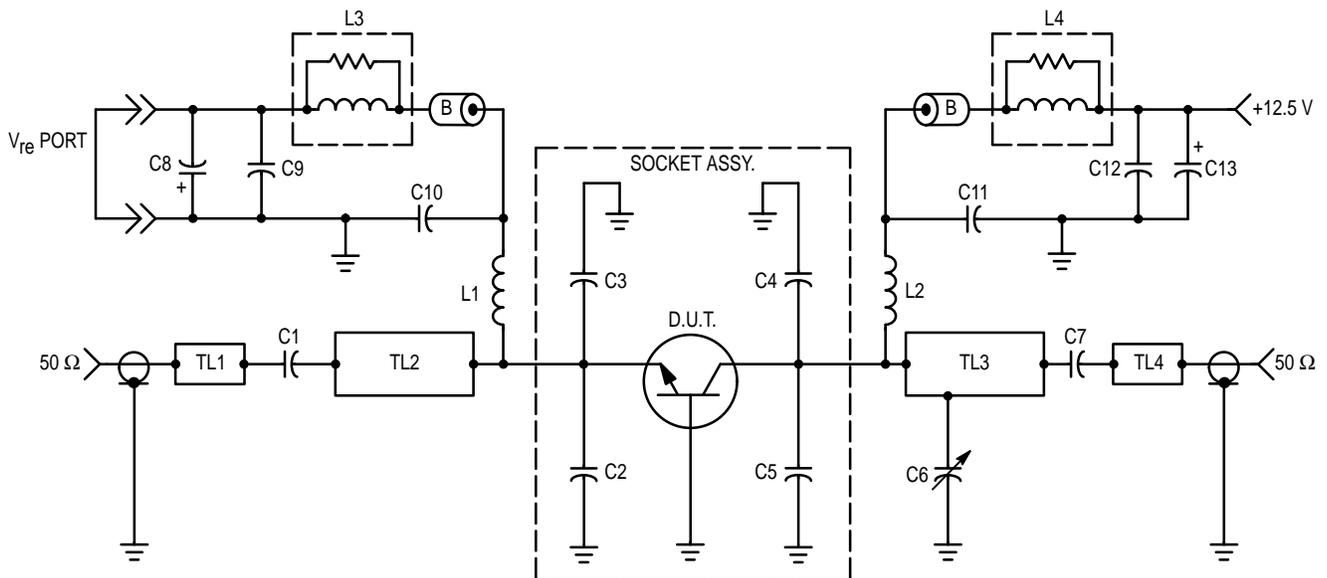
| Characteristic  | Symbol        | Min  | Typ | Max | Unit |
|---|---------------|------|-----|-----|------|
| Emitter–Base Breakdown Voltage<br>( $I_E = 5.0 \text{ mAdc}$ , $I_C = 0$ )        | $V_{(BR)EBO}$ | 4.0  | —   | —   | Vdc  |
| Collector–Emitter Breakdown Voltage<br>( $I_C = 50 \text{ mAdc}$ , $I_B = 0$ )    | $V_{(BR)CEO}$ | 16.5 | —   | —   | Vdc  |
| Collector–Emitter Breakdown Voltage<br>( $I_C = 50 \text{ mAdc}$ , $V_{BE} = 0$ ) | $V_{(BR)CES}$ | 38   | —   | —   | Vdc  |
| Collector Cutoff Current<br>( $V_{CE} = 15 \text{ Vdc}$ , $V_{BE} = 0$ )          | $I_{CES}$     | —    | —   | 10  | mAdc |

(continued)



**ELECTRICAL CHARACTERISTICS — continued** ( $T_C = 25^\circ\text{C}$  unless otherwise noted.)

| Characteristic  | Symbol   | Min                            | Typ | Max | Unit |
|---|----------|--------------------------------|-----|-----|------|
| <b>ON CHARACTERISTICS</b>   |          |                                |     |     |      |
| DC Current Gain<br>( $I_C = 2.0 \text{ Adc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )   | $h_{FE}$ | 40                             | 65  | 120 | —    |
| <b>DYNAMIC CHARACTERISTICS</b>  |          |                                |     |     |      |
| Output Capacitance<br>( $V_{CB} = 12.5 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )   | $C_{ob}$ | —                              | 75  | 90  | pF   |
| <b>FUNCTIONAL TESTS</b>   |          |                                |     |     |      |
| Common-Base Amplifier Power Gain<br>( $V_{CC} = 12.5 \text{ Vdc}$ , $P_{out} = 45 \text{ W}$ , $f = 870 \text{ MHz}$ )                  | $G_{PB}$ | 4.5                            | 5.5 | —   | dB   |
| Collector Efficiency<br>( $V_{CC} = 12.5 \text{ Vdc}$ , $P_{out} = 45 \text{ W}$ , $f = 870 \text{ MHz}$ )                              | $\eta_c$ | 60                             | 68  | —   | %    |
| Load Mismatch<br>( $V_{CC} = 15.5 \text{ Vdc}$ , $P_{in} = 16 \text{ W}$ , $f = 870 \text{ MHz}$ ,<br>$VSWR = 10:1$ , All Phase Angles) | $\psi$   | No Degradation in Output Power |     |     |      |



- C1 — 51 pF, 100 mil Chip Capacitor
- C2 — 12 pF, Mini-Underwood
- C3 — 11 pF, Mini-Underwood
- C4, C5 — 21 pF, Mini-Underwood
- C6 — 0.08–8.0 pF Johansen Gigatrim
- C7 — 47 pF, 100 mil Chip Capacitor
- C8, C13 — 10  $\mu\text{F}$ , 25 WV Electrolytic Capacitor
- C9, C12 — 1000 pF Unelco J101

- C10, C11 — 91 pF Mini-Underwood
- L1, L2 — 4 Turns #18 Enameled, 200 mil ID
- L3, L4 — 12 Turns #22 Enameled, Wound Over 10  $\Omega$  Resistor
- TL1, TL4 — 50  $\Omega$  Microstrip Line
- TL2 — Microstrip ( $Z_0 = 38 \text{ ohms}$ ,  $\lambda/4$  @ 838 MHz)
- TL3 — Microstrip ( $Z_0 = 28 \text{ ohms}$ ,  $\lambda/4$  @ 838 MHz)
- Board Material — 0.032" Glass-Teflon, 2 oz. cu. clad,  $\epsilon_r = 2.56$
- B — Ferrite Bead, Ferroxcube 56-590-65-3B

**Figure 1. 806–870 MHz Broadband Test Circuit**

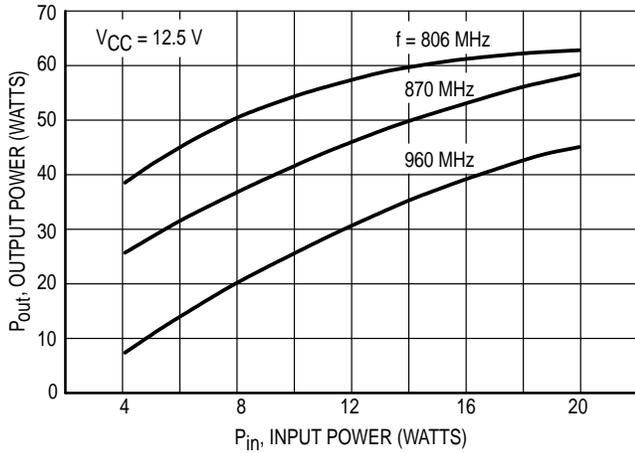


Figure 2. Output Power versus Input Power

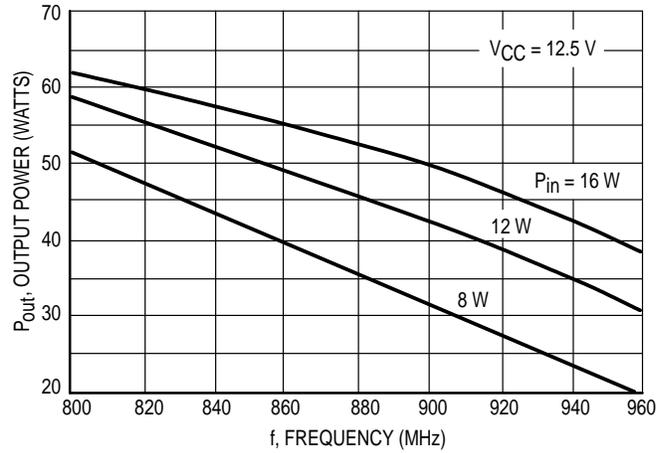


Figure 3. Output Power versus Frequency

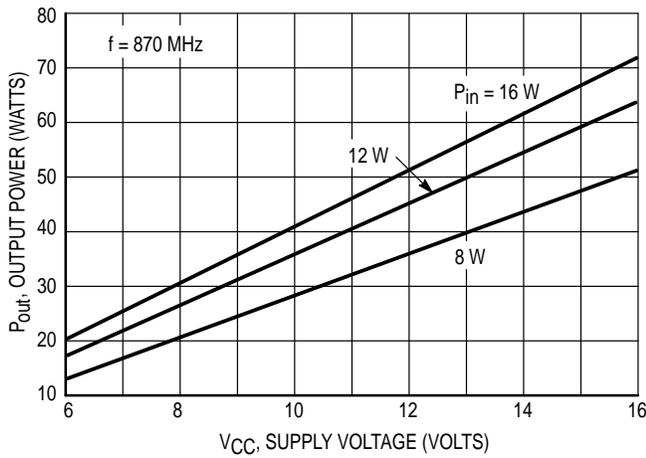


Figure 4. Output Power versus Supply Voltage

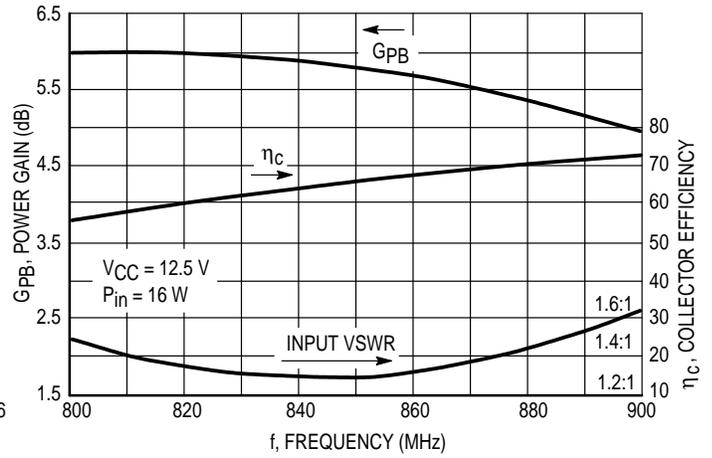


Figure 5. Typical Broadband Circuit Performance

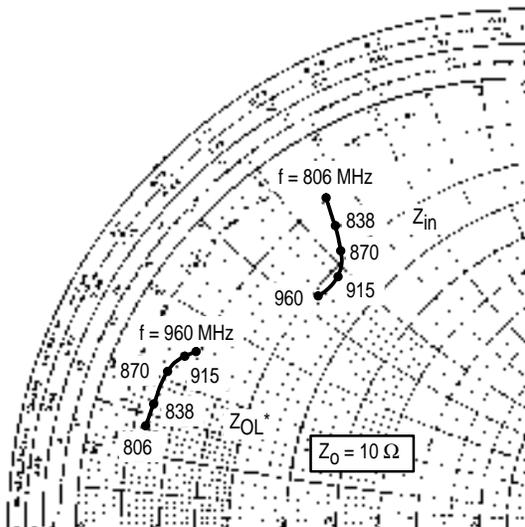


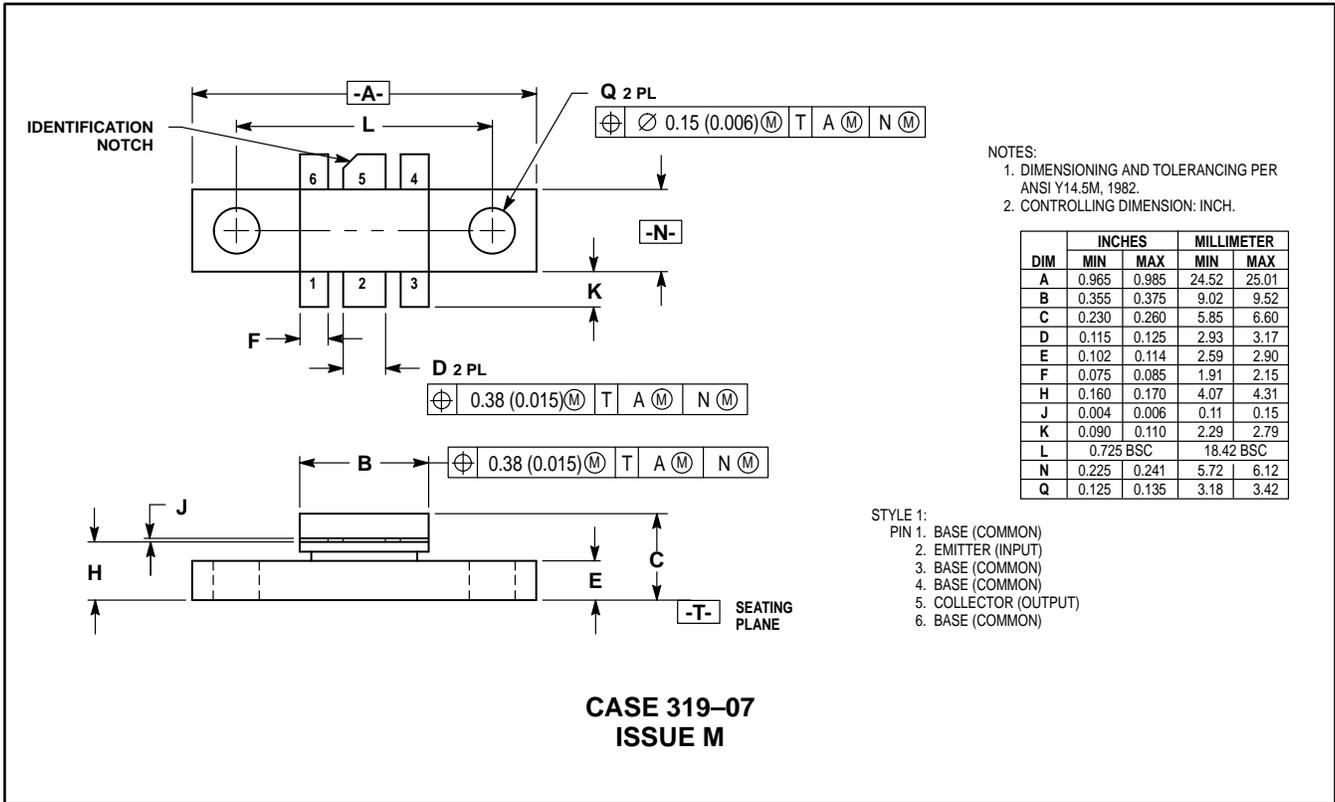
Figure 6. Series Equivalent Input/Output Impedances

$V_{CC} = 12.5 \text{ Vdc}, P_{in} = 16 \text{ W}, P_{out} = 45 \text{ W}$

| f (MHz) | $Z_{in}$ (Ohms) | f (MHz) | $Z_{OL}^*$ (Ohms) |
|---------|-----------------|---------|-------------------|
| 806     | 0.99 +j5.52     | 806     | 0.67 +j1.33       |
| 838     | 1.48 +j5.47     | 838     | 0.68 +j1.66       |
| 870     | 1.79 +j5.25     | 870     | 0.72 +j2.16       |
| 915     | 2.12 +j4.80     | 915     | 0.83 +j2.40       |
| 960     | 2.11 +j4.28     | 960     | 0.99 +j2.50       |

$Z_{OL}^*$  = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

## PACKAGE DIMENSIONS



NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES    |       | MILLIMETER |       |
|-----|-----------|-------|------------|-------|
|     | MIN       | MAX   | MIN        | MAX   |
| A   | 0.965     | 0.985 | 24.52      | 25.01 |
| B   | 0.355     | 0.375 | 9.02       | 9.52  |
| C   | 0.230     | 0.260 | 5.85       | 6.60  |
| D   | 0.115     | 0.125 | 2.93       | 3.17  |
| E   | 0.102     | 0.114 | 2.59       | 2.90  |
| F   | 0.075     | 0.085 | 1.91       | 2.15  |
| H   | 0.160     | 0.170 | 4.07       | 4.31  |
| J   | 0.004     | 0.006 | 0.11       | 0.15  |
| K   | 0.090     | 0.110 | 2.29       | 2.79  |
| L   | 0.725 BSC |       | 18.42 BSC  |       |
| N   | 0.225     | 0.241 | 5.72       | 6.12  |
| Q   | 0.125     | 0.135 | 3.18       | 3.42  |

STYLE 1:  
 PIN 1. BASE (COMMON)  
 PIN 2. EMITTER (INPUT)  
 PIN 3. BASE (COMMON)  
 PIN 4. BASE (COMMON)  
 PIN 5. COLLECTOR (OUTPUT)  
 PIN 6. BASE (COMMON)

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